

DATASHEET

6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER 4N2X Series 4N3X Series H11AX Series







Features:

- 4N2X series: 4N25, 4N26, 4N27, 4N28
- 4N3X series: 4N35, 4N36, 4N37, 4N38
- H11AX series: H11A1, H11A2, H11A3, H11A4, H11A5
- High isolation voltage between input and output (Viso=5000 V rms)
- Creepage distance >7.62 mm
- Operating temperature up to +110°C
- Compact dual-in-line package
- •The product itself will remain within RoHS compliant version •Compliance with EU REACH
- UL and cUL approved(No. E214129)
- VDE approved (No. 132249)
- SEMKO approved
- NEMKO approval
- DEMKO approval
- FIMKO approval
- CQC approved

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Description

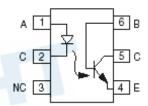
The 4N2X, 4N3X, H11AX series of devices each consist of an infrared emitting diode optically coupled to a phototransistor.

They are packaged in a 6-pin DIP package and available in wide-lead spacing and SMD option.

Applications

- Power supply regulators
- Digital logic inputs
- Microprocessor inputs

Schematic



Pin Configuration

- 1. Anode
- 2. Cathode
- 3. No Connection
- 4. Emitter
- 5. Collector
- 6. Base

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Absolute Maximum Ratings (Ta=25℃)

	Parameter	Symbol	Rating	Unit
	Forward current	Ι _F	60	mA
	Peak forward current (t = 10µs)	I _{FM}	1	А
Input	Reverse voltage	V _R	6	V
	Power dissipation ($T_A = 25^{\circ}C$)	D	100	mW
	Derating factor (above 100°C)	P _D	3.8	mW/°C
	Collector-Emitter voltage	V _{CEO}	80	V
	Collector-Base voltage	V _{CBO}	80	V
0.14.1	Emitter-Collector voltage	V _{ECO}	V _{ECO} 7	
Output	Emitter-Base voltage	V _{EBO}	7	V
	Power dissipation ($T_A = 25^{\circ}C$)	D	150	mW
	Derating factor (above 100°C)	P _c —	9.0	mW/°C
Total Power Dissipation		P _{TOT}	200	mW
Isolation Voltage*1		V _{ISO}	5000	V rms
Operating Temperature		T _{OPR}	-55 to 110	°C
Storage Temperature		T _{STG}	-55 to 125	°C
Soldering Temperature* ²		T _{SOL}	T _{SOL} 260	

Notes:

*1 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1, 2 & 3 are shorted together, and pins 4, 5 & 6 are shorted together. *2 For 10 seconds

Electro-Optical Characteristics (Ta=25 $^\circ\!\!\mathrm{C}$ unless specified otherwise)

Input						
Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Forward voltage	V _F	-	1.2	1.5	V	I _F = 10mA
Reverse current	I _R	-	-	10	μA	V _R = 6V
Input capacitance	C _{in}	-	30	-	pF	V = 0, f = 1MHz
Output						
Parameter	Symbol	Min	Тур.	Max.	Unit	Condition
Collector-Base dark current	I _{CBO}	-	-	20	nA	V _{CB} = 10V
4N2X Collector- Emitter H11AX	– I _{CEO}	-	-	50	nA	V _{CE} = 10V, IF=0mA
dark current 4N3X		-	-	50		V _{CE} = 60V, IF=0mA
Collector-Emitter breakdown voltage	BV _{CEO}	80	-		V	l _c =1mA
Collector-Base breakdown voltage	BV _{CBO}	80	-		V	I _C =0.1mA
Emitter-Collector breakdown voltage	BV _{ECO}	7	-	-	V	I _E =0.1mA
Emitter-Base breakdown voltage	BV _{EBO}	7	-	-	V	I _E =0.1mA
Collector-Emitter capacitance	C_{CE}	-	8	-	pF	VCE=0V, f=1MHz

* Typical values at T_a = 25°C

Transfer Characteristics

Parameter		Symbol	Min	Тур.	Max.	Unit	Condition
	4N35, 4N36, 4N37		100	-	-	%	I _F = ±10mA ,V _{CE} = 10V
	H11A1	_	50	-	-		
Current Transfer	H11A5	CTR	30	-	-		
ratio	4N25, 4N26, 4N38, H11A2, H11A3		20	-	-		
	4N27, 4N28, H11A4		10	-	-		
	4N25, 4N26, 4N27, 4N28		-	-	0.5	V	$I_{F} = 50 mA$, $I_{c} = 2 mA$
Collector- Emitter	4N35, 4N36, 4N37	-	-	-	0.3		I _F = 10mA, I _c = 0.5mA
saturation voltage	H11A1,H11A2, H11A3,H11A4, H11A5	V _{CE(sat)}	-	-	0.4		
	4N38	-	-	-	1.0		$I_{\rm F} = 20 {\rm mA}, \ I_{\rm c} = 4 {\rm mA}$
Isolation resi	Isolation resistance		10 ¹¹	-	-	Ω	$V_{IO} = 500 V dc$
Input-output	Input-output capacitance		-	0.2	-	pF	$V_{IO} = 0, f = 1MHz$
4N25, 4N26, 4N27, 4N28, H11A1,H11A2, H11A3,H11A4, Turn-on time H11A5		Ton		3	10	μs	V_{CC} = 10V, I _F = 10mA, R _L = 100 Ω See Fig. 11
	4N35, 4N36, 4N37, 4N38		-	10	12		$V_{CC} = 10V$, $I_C = 2mA$, $R_L = 100\Omega$, See Fig. 11
Turn-off time	4N25, 4N26, 4N27, 4N28, H11A1,H11A2, H11A3,H11A4, H11A5	Toff	-	3	10	μs	V_{CC} = 10V, I _F = 10mA, R _L = 100 Ω See Fig. 11
	4N35, 4N36, 4N37, 4N38		-	9	12		$V_{CC} = 10V$, $I_C = 2mA$, $R_L = 100\Omega$, See Fig. 11

* Typical values at T_a = 25°C

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Typical Electro-Optical Characteristics Curves

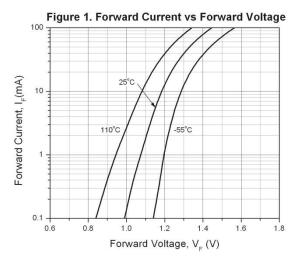
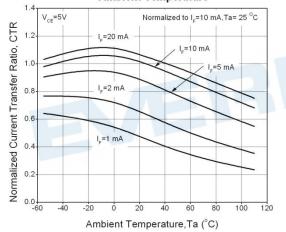
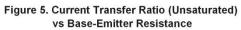
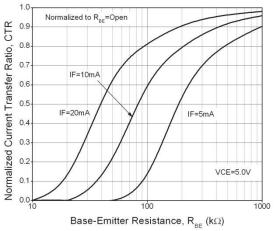


Figure 3. Current Tranfer Ratio vs Ambient Temperature







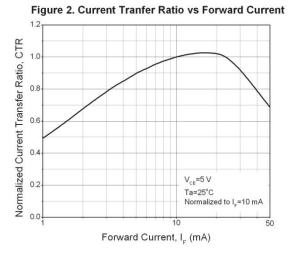
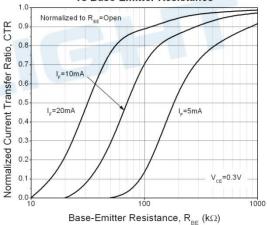


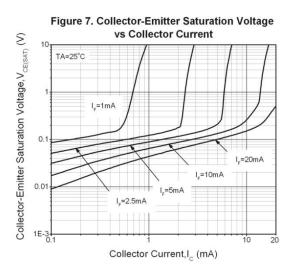
Figure 4. Current Transfer Ratio (Saturated) vs Base-Emitter Resistance

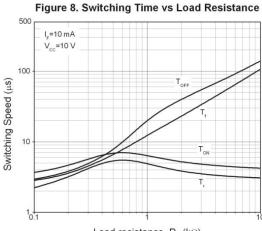


10000 V_{CE}= 10 V 1000 Collector Dark Current, I_{CEO} (nA) 100 10 0.1 0.01 1E-3 -60 -40 40 60 80 100 .20 120 Ambient Temperature, Ta (°C)

Figure 6. Dark Current vs Ambient Temperature

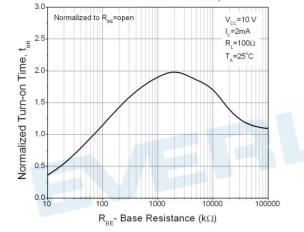
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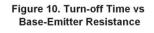


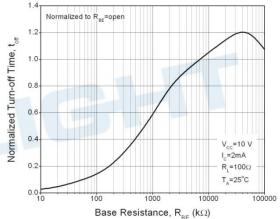


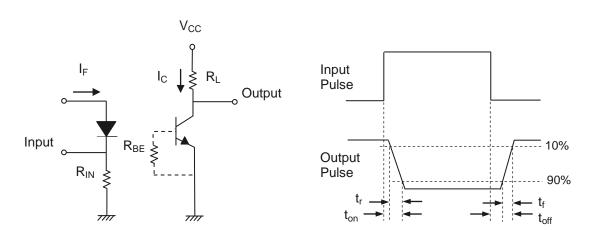
Load resistance, ${\sf R}_{_{\sf L}}$ (k $\!\Omega\!)$

Figure 9. Turn-on Time vs Base-Emitter Resistance)







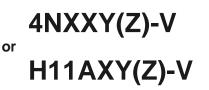






Order Information

Part Number



Note

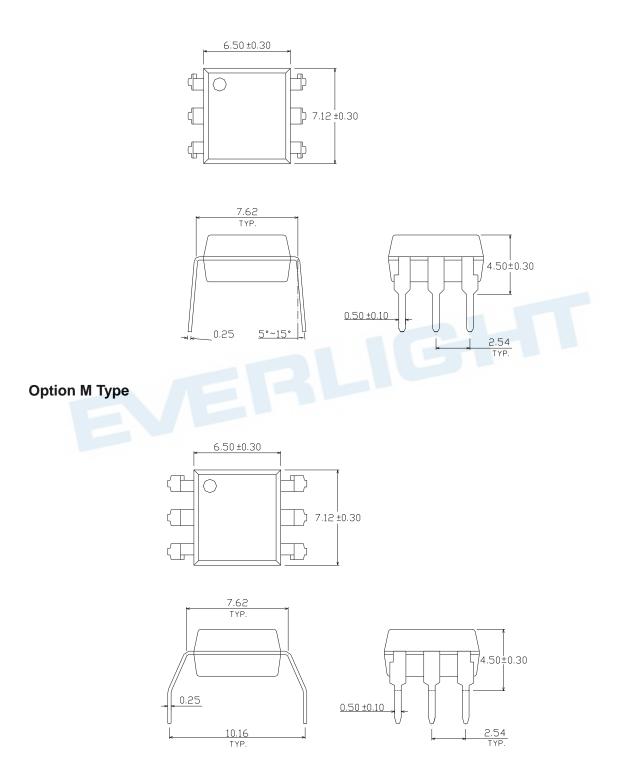
- XX = Part no. for 4NXX series (25, 26, 27, 28, 35, 36, 37 or 38)
- X = Part no. for H11AX series (1, 2, 3, 4, or 5)
- Y = Lead form option (S, S1, M or none)
- Z = Tape and reel option (TA, TB or none).
- V = VDE safety (optional)

Option	Description	Packing quantity	
None	Standard DIP-6	65 units per tube	
М	Wide lead bend (0.4 inch spacing)	65 units per tube	
S (TA)	Surface mount lead form + TA tape & reel option	1000 units per reel	
S (TB)	Surface mount lead form + TB tape & reel option 1000 units per reel		
S1 (TA)	Surface mount lead form (low profile) + TA tape & reel option	1000 units per reel	
S1 (TB)	Surface mount lead form (low profile) + TB tape & reel option	1000 units per reel	

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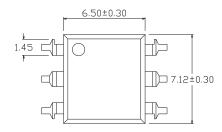
Package Dimension (Dimensions in mm)

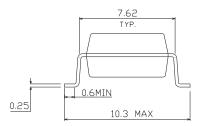
Standard DIP Type

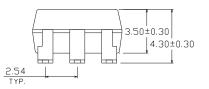


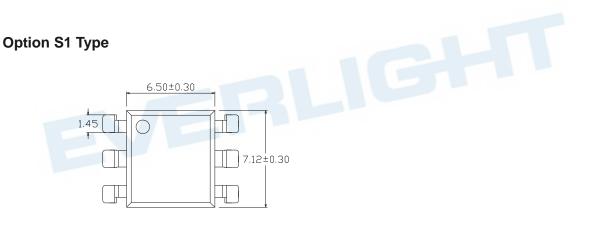


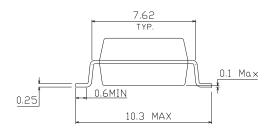
Option S Type

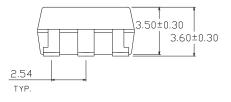






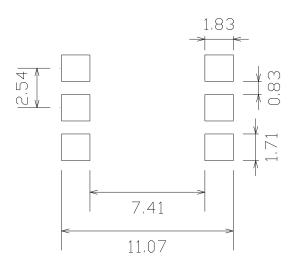








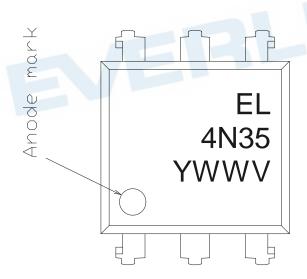
Recommended pad layout for surface mount leadform



Notes

Suggested pad dimension is just for reference only. Please modify the pad dimension based on individual need.

Device Marking

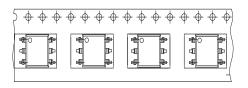


Notes

EL	denotes Everlight
4N35	denotes Device Number
Y	denotes 1 digit Year code
WW	denotes 2 digit Week code
V	denotes VDE (optional)

Tape & Reel Packing Specifications

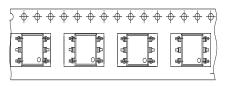
Option TA





Direction of feed from reel

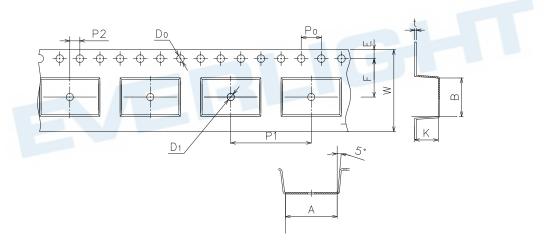
Option TB





Direction of feed from reel

Tape dimensions

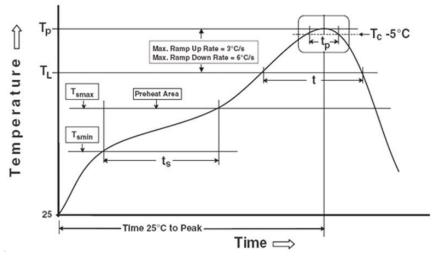


Dimension No.	А	В	Do	D1	E	F
Dimension (mm)	10.8±0.1	7.55±0.1	1.5±0.1	1.5+0.1/-0	1.75±0.1	7.5±0.1
Dimension No.	Ро	P1	P2	t	w	к
Dimension (mm)	4.0±0.15	12±0.1	2.0±0.1	0.35±0.03	16.0±0.2	4.5±0.1



Precautions for Use

- 1. Soldering Condition
 - 1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note:

Preheat

Temperature min (T_{smin}) Temperature max (T_{smax}) Time $(T_{smin} \text{ to } T_{smax})$ (t_s) Average ramp-up rate $(T_{smax} \text{ to } T_p)$

150 °C 200°C 60-120 seconds 3 °C/second max

Reference: IPC/JEDEC J-STD-020D

Other Liquidus Temperature (T_L) Time above Liquidus Temperature (t_L) Peak Temperature (T_P) Time within 5 °C of Actual Peak Temperature: T_P - 5°C Ramp- Down Rate from Peak Temperature Time 25°C to peak temperature

Reflow times

217 °C 60-100 sec 260°C 30 s 6°C /second max. 8 minutes max. 3 times

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